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SEMICONDUCTOR PHYSICS

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Luo Yimin, Chen Zhenhua, and Chen Ding
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Zhu Xinghua, Yang Dingyu, Wei Zhaorong, Sun Hui, Wang Zhiguo, and Zu Xiaotao
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Cao Jie, Qu Shengchun, Liu Kong, and Wang Zhanguo
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Lei Li, Zhao Gaoyang, Xu Hui, and Zhao Juanjuan
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Zhang Huafu, Liu Hanfa, Lei Chengxin, Zhou Aiping, and Yuan Changkun

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Feng Zhihong, Xie Shengyin, Zhou Rui, Yin Jiayun, Zhou Wei, and Cai Shujun
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Li Hairong and Li Siyuan

(Continued on inside back cover)

- 084006 Design and application of a depletion-mode NJFET in a high-voltage BiCMOS process (4 pages)**
Liu Yong, Tang Zhaojun, Wang Zhikuan, Yang Yonghui, Yang Weidong, and Hu Yonggui
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Zhao Jianzhi, Lin Zhaojun, Lü Yuanjie, Corrigan Timothy D, Meng Lingguo, Zhang Yu, Wang Zhanguo, and Chen Hong
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Zhang Han, Chen Nuofu, Wang Yu, Yin Zhigang, Zhang Xingwang, Shi Huiwei, Wang Yanshuo, and Huang Tianmao
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Gao Huanmei, Luo Xiaorong, Zhang Wei, Deng Hao, and Lei Tianfei

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Liang Yong, Wang Zhigong, Meng Qiao, and Guo Xiaodan
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